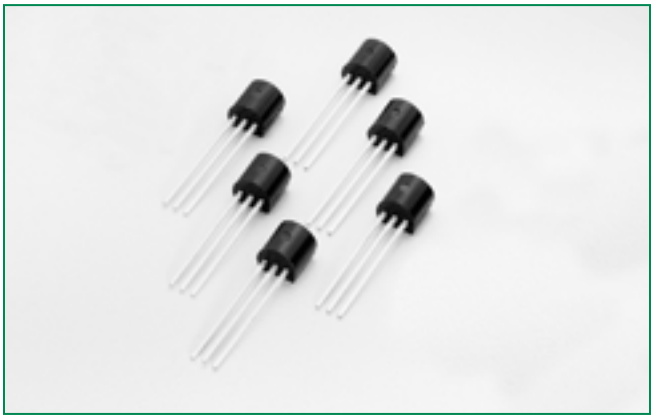
Thyristors
1.5 Amp Sensitive SCRs

S602ECS

HF RoHS



Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	1.5	A
V_{DRM}/V_{RRM}	600	V
I_{GT}	100	µA

Applications

The S602ECS is specifically designed for Gas Ignition applications that require high pulse surge current capability.

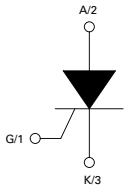
Description

This new 1.5 A sensitive gate SCR in an TO-92 package with a G-A-K pin out, offers a high static component series with a high static dv/dt and a low turn off (tq) time by the use of small die planar construction implementation.

Features

- Surge capability >15Amps
- High dv/dt noise immunity
- Improved turn-off time (t_q) ≤ 35 µsec.
- TO-92 G-A-K pinout
- Sensitive gate for direct microprocessor interface
- RoHS compliant and Halogen-Free

Schematic Symbol



Absolute Maximum Ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	T_C = 65°C		1.5	A
$I_{T(AV)}$	Average on-state current	T_C = 65°C		0.95	A
I_{TSM}	Non repetitive surge peak on-state current (Single cycle, T_J initial = 25°C)		F = 50 Hz	14.0	A
			F = 60 Hz	16.8	
I^2t	I^2t Value for fusing	t_p = 10 ms	F = 50 Hz	0.78	A^2s
		t_p = 8.3 ms	F = 60 Hz	0.93	
di/dt	Critical rate of rise of on-state current IG = 10mA		T_J = 125°C	50	A/µs
I_{GM}	Peak gate current	t_p = 10 µs	T_J = 125°C	1.0	A
$P_{G(AV)}$	Average gate power dissipation		T_J = 125°C	0.1	W
T_{stg}	Storage junction temperature range			-40 to 150	°C
T_J	Operating junction temperature range			-40 to 125	°C

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Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	S602ECS		Unit
			Min	Max	
I_{GT}	DC Gate Trigger Current	V_D = 12V R_L = 60 Ω	20	100	µA
V_{GT}	DC Gate Trigger Voltage		—	0.8	V
V_{GRM}	Peak Reverse Gate Voltage	I_{RG} = 10µA	5	—	V
I_H	Holding Current	R_{GK} = 1 kΩ	—	3	mA
(dv/dt)s	Critical Rate-of-Rise of Off-State Voltage	T_J = 125°C $V_D = V_{DRM}/ V_{RRM}$ Exponential Waveform R_{GK} = 1 kΩ	50	—	V/µs
t_q	Turn-Off Time	T_J = 125°C @ 600 V R_{GK} = 1 kΩ	—	35	µs
t_{gt}	Turn-On Time	I_G = 10mA PW = 15µsec I_T = 3.0A (pk)	—	3	µs

Static Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Value		Unit
			Min	Max	
V_{TM}	Peak On-State Voltage	I_{TM} = 4A (pk)	—	1.8	V
I_{DRM}	Off-State Current, Peak Repetitive	T_J = 25°C @ $V_D = V_{DRM}$ R_{GK} = 1 kΩ	—	5	µA
		T_J = 125°C @ $V_D = V_{DRM}$ R_{GK} = 1 kΩ	—	500	µA

Thermal Resistances

Symbol	Parameter		Value	Unit
$R_{\theta(JC)}$	Junction to case (AC)	I_T = 1.5A $_{(RMS)}$, 60Hz AC resistive load condition, 100% conduction.	50	°C/W
$R_{\theta(J-A)}$	Junction to ambient		160	°C/W

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

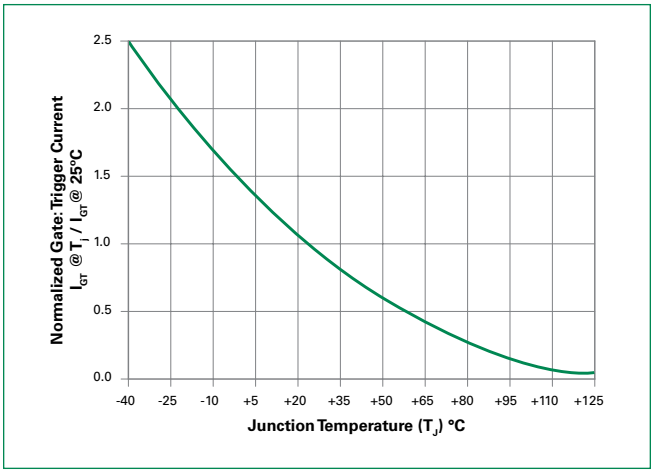

Figure 2: Normalized DC Holding Current vs. Junction Temperature

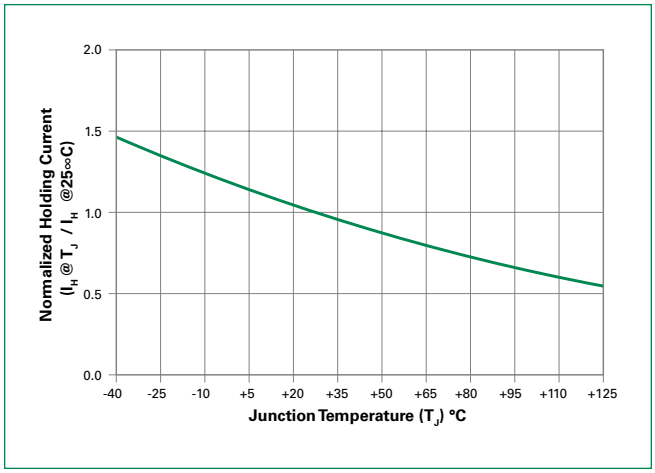

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Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature

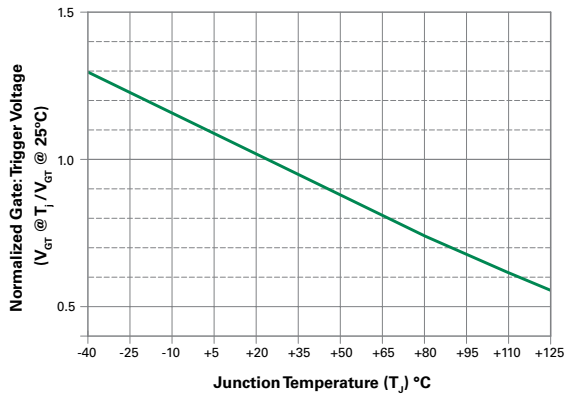


Figure 4: On-State Current vs. On-State Voltage (Typical)

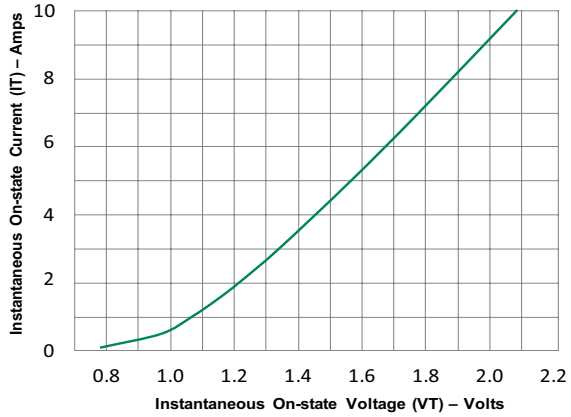


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

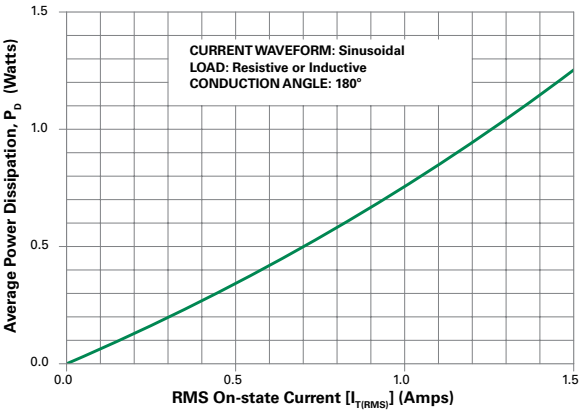


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

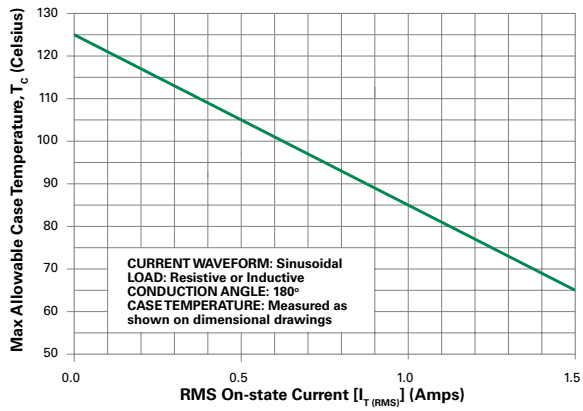
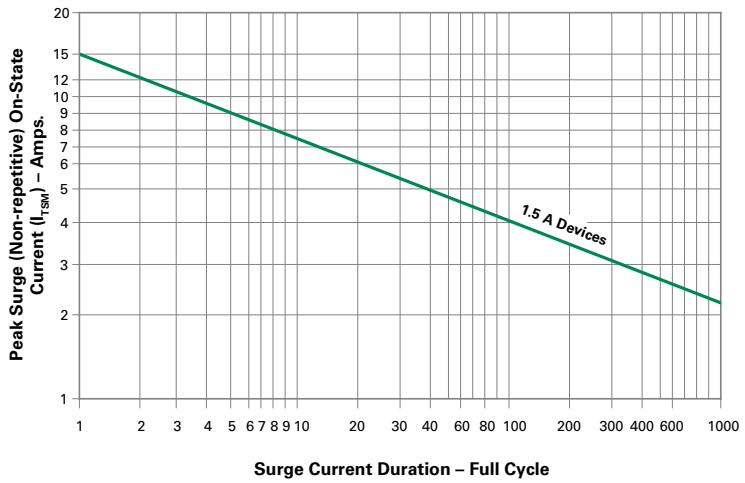


Figure 6: Surge Peak On-State Current vs. Number of Cycles



Supply Frequency: 60Hz Sinusoidal
Load: Resistive
RMS On-State Current [$I_{T(RMS)}$]: Max Rated Value at Specific Case Temperature

Notes:
1. Gate control may be lost during and immediately following surge current interval.
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

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Figure 7: Typical DC Gate Trigger Current with R_{GK} vs. Junction Temperature

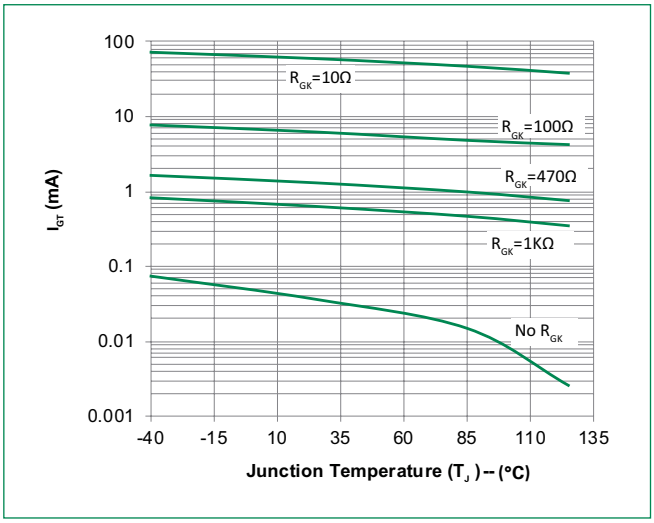


Figure 8: Typical DC Holding Current with R_{GK} vs. Junction Temperature

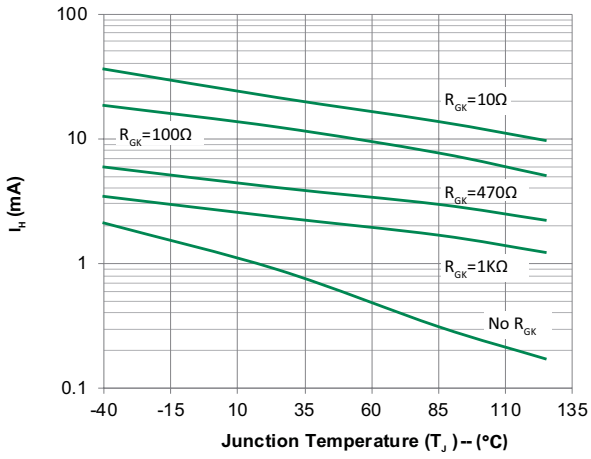


Figure 9: Typical turn off time with R_{GK} vs. Junction Temperature

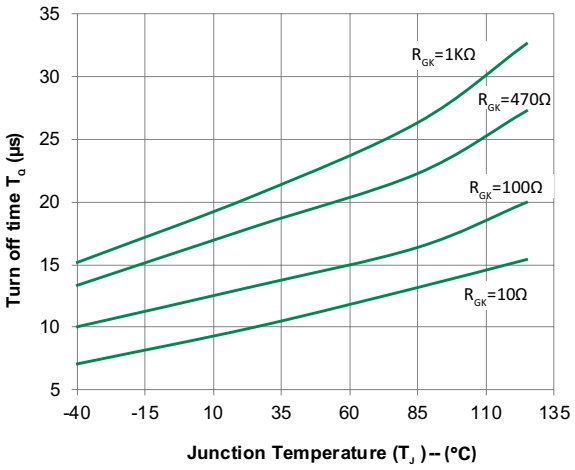
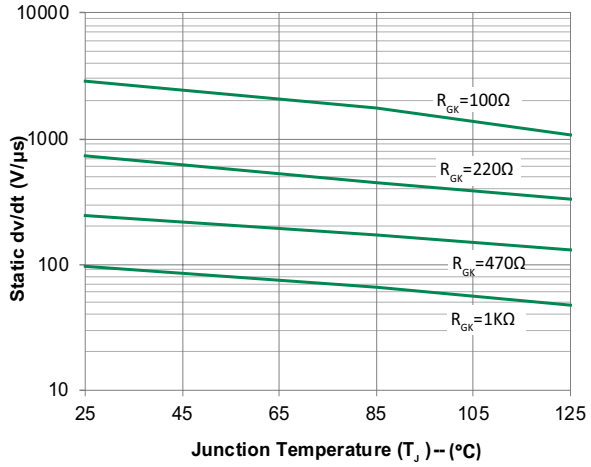


Figure 10: Typical Static dv/dt with RGK vs. Junction Temperature



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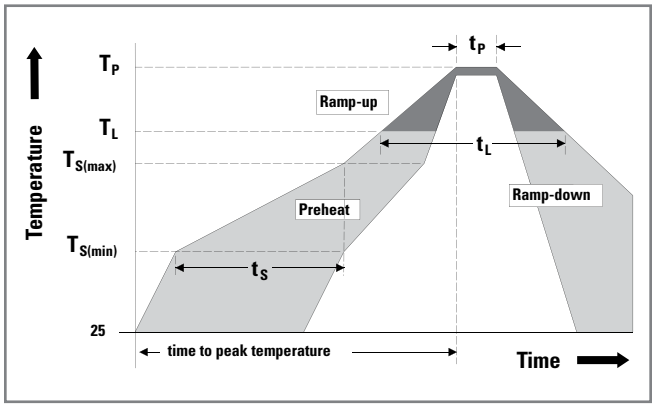
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ($T_{s(min)}$)	150°C
	-Temperature Max ($T_{s(max)}$)	200°C
	-Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	-Temperature (T_L) (Liquidus)	217°C
	-Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_P)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated.
Body Material	UL Recognized compound meeting flammability rating V-0.
Lead Material	Copper Alloy

Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

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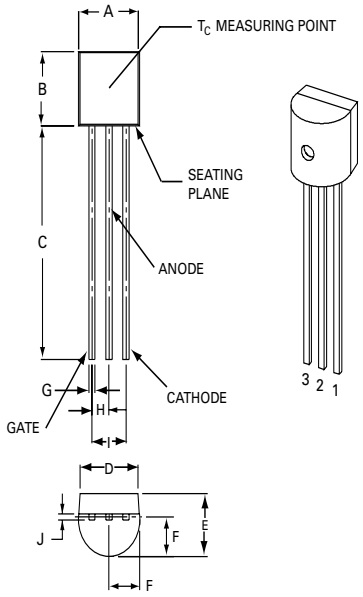
Dimensions

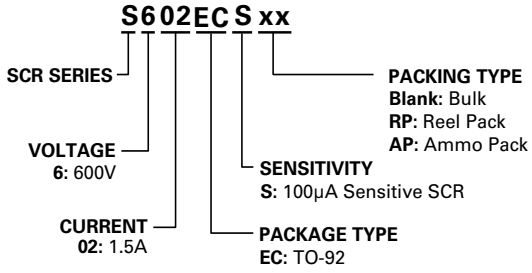


Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.175	0.205	4.450	5.200
B	0.170	0.210	4.320	5.330
C	0.500	—	12.700	—
D	0.135	—	3.430	—
E	0.125	0.165	3.180	4.190
F	0.080	0.105	2.040	2.660
G	0.016	0.021	0.407	0.533
H	0.045	0.055	1.150	1.390
I	0.095	0.105	2.420	2.660
J	0.015	0.020	0.380	0.500

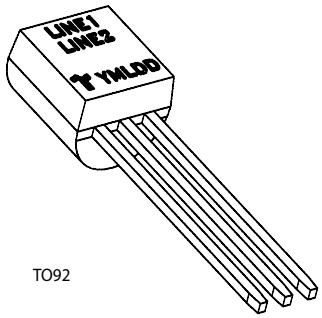
Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
S602ECS	S602ECS	0.170 g	Bulk	2500
S602ECSAP	S602ECS	0.170 g	Ammo Pack	2000
S602ECSRP	S602ECS	0.170 g	Tape & Reel	2000

Part Numbering System



Part Marking System



TO92

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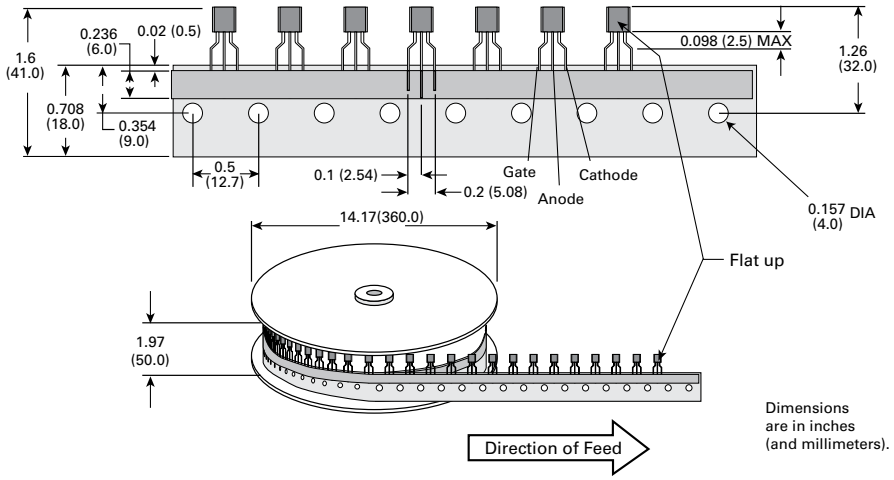
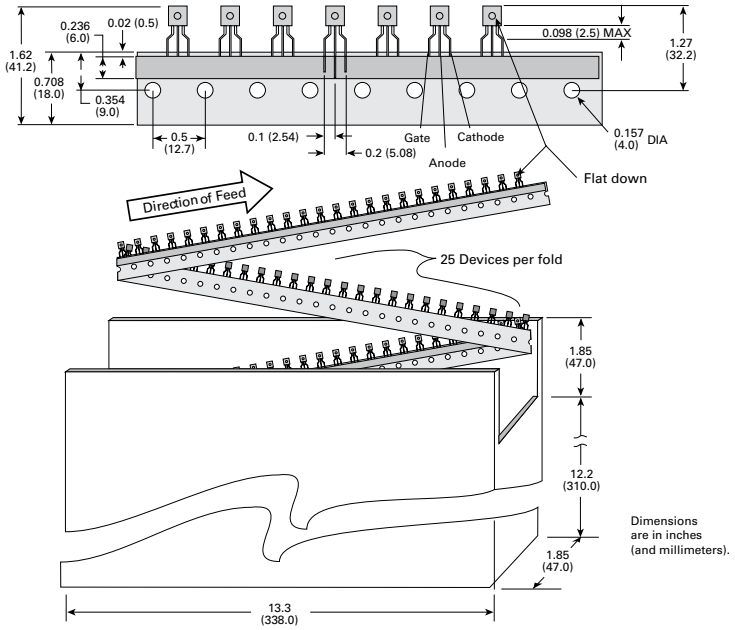
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-C Standards



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